CMOS QUAD EXCLUSIVE-NOR GATE

FEATURES

- **Buffered Outputs**
- **Diode Protection on all Inputs**
- **Fully "B"-Series Compatible**

DESCRIPTION

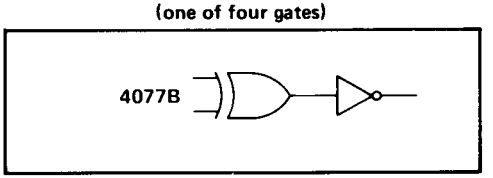
The 4077B contains four independent exclusive-NOR gates integrated on a single monolithic silicon chip. Each exclusive-NOR gate consists of five N-channel and five P-channel enhancement-mode transistors, plus output buffering devices.

TRUTH TABLE
(one of four gates)

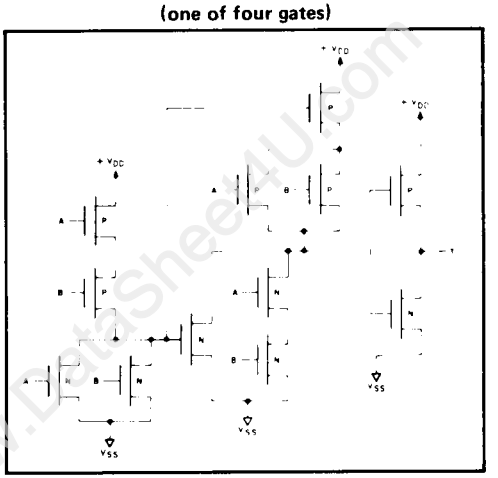
A	B	Y
0	0	1
1	0	0
0	1	0
1	1	1

Where 1 = High Level
0 = Low Level

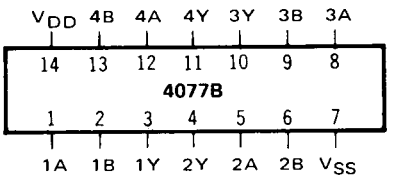
LOGIC DIAGRAM
(one of four gates)



SCHEMATIC DIAGRAM
(one of four gates)



CONNECTION DIAGRAM
(all packages)



Add suffix for package:

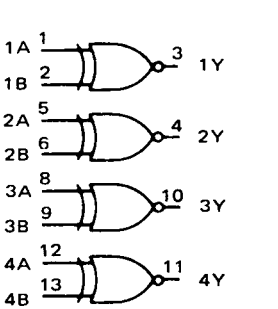
C	14-pin Cerdip
D	14-pin Ceramic
E	14-pin Epoxy
F	14-pin Flat
H	Chip

RECOMMENDED OPERATING CONDITIONS

For maximum reliability:

DC Supply Voltage	$V_{DD} - V_{SS}$	3 to 15	Vdc
Operating Temperature	T_A		
C, D, F, H Device		-55 to +125	°C
E Device		-40 to +85	°C

FUNCTION DIAGRAM



ELECTRICAL CHARACTERISTICS

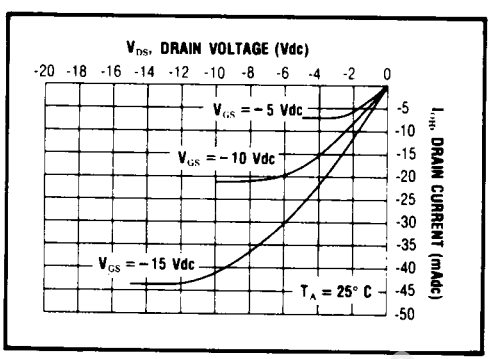
STATIC CHARACTERISTICS [1]

PARAMETER		V_{DD} (Vdc)	CONDITIONS	T_{LOW} [2]		+25°C			T_{HIGH} [2]		Units
				Min.	Max.	Min.	Typ.	Max.	Min.	Max.	
QUIESCENT DEVICE CURRENT	I_{DD}	5	$V_{IN} = V_{SS}$ or V_{DD}	–	0.05	–	0.0005	0.05	–	1.5	μAdc
		10	All valid input	–	0.10	–	0.001	0.10	–	3.0	
		15	combinations	–	0.20	–	0.002	0.20	–	6.0	

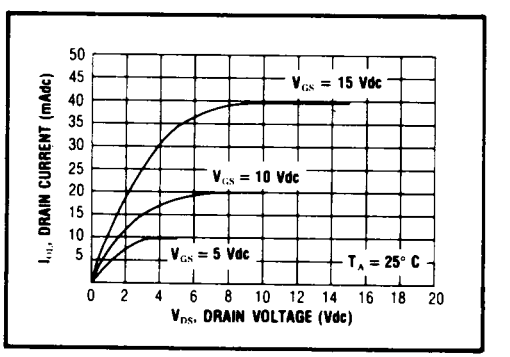
NOTES: [1] Remaining Static Electrical Characteristics are listed under "4000B Series Family Specifications".
[2] T_{LOW} = -55°C for C, D, F, H device.
= -40°C for E device.
T_{HIGH} = +125°C for C, D, F, H device.
= + 85°C for E device.

DYNAMIC CHARACTERISTICS (C_L = 50pF, T_A = 25°C)

PARAMETER		V_{DD} (Vdc)	Min.	Typ.	Max.	Units
PROPAGATION DELAY TIME	t_{PLH}, t_{PHL}	5	–	150	300	ns
		10	–	65	130	
		15	–	50	100	
OUTPUT TRANSITION TIME	t_{TLH}, t_{THL}	5	–	100	200	ns
		10	–	50	100	
		15	–	40	80	



Typical P-Channel
Source Current Characteristics



Typical N-Channel
Sink Current Characteristics